

Raytheon

399-851

RC4227CN

# RC/RM4227 Precision Monolithic Dual Operational Amplifier

## Features

- Very low noise  
Spectral noise density —  $3.0\text{nV}/\sqrt{\text{Hz}}$   
1/f noise corner frequency — 2.7Hz
- Very low  $V_{OS}$  drift  
 $0.2\mu\text{V}/\text{Mo}$   
 $0.2\mu\text{V}/^\circ\text{C}$
- High gain —  $1.8 \times 10^6\text{V/V}$
- High output drive capability —  $\pm 10\text{V}$  into 1K load
- High slew rate —  $2.7\text{V}/\mu\text{S}$
- Wide gain bandwidth product — 8MHz
- Good common mode rejection ratio — 126dB
- Low input offset voltage —  $20\mu\text{V}$  typ
- Low frequency noise —  $0.08\mu\text{V}_{\text{p-p}}$  0.1Hz to 10Hz
- Low input offset current — 9nA typ
- Standard dual 8-lead pinout

## Description

The 4227 is designed for instrumentation grade signal conditioning where low noise (both spectral density and burst), wide bandwidth, and high slew rate are required along with low input offset voltage, low input offset temperature coefficient, and low input bias currents. These features are all available in a device which is internally compensated for excellent phase

margin ( $70^\circ$ ) in a unity gain configuration. Digital nulling techniques performed at wafer sort make it feasible to guarantee temperature stable input offset voltages as low as  $75\mu\text{V}$  max. Input bias current cancellation techniques are used to obtain  $\pm 55\text{nA}$  max. input bias currents.

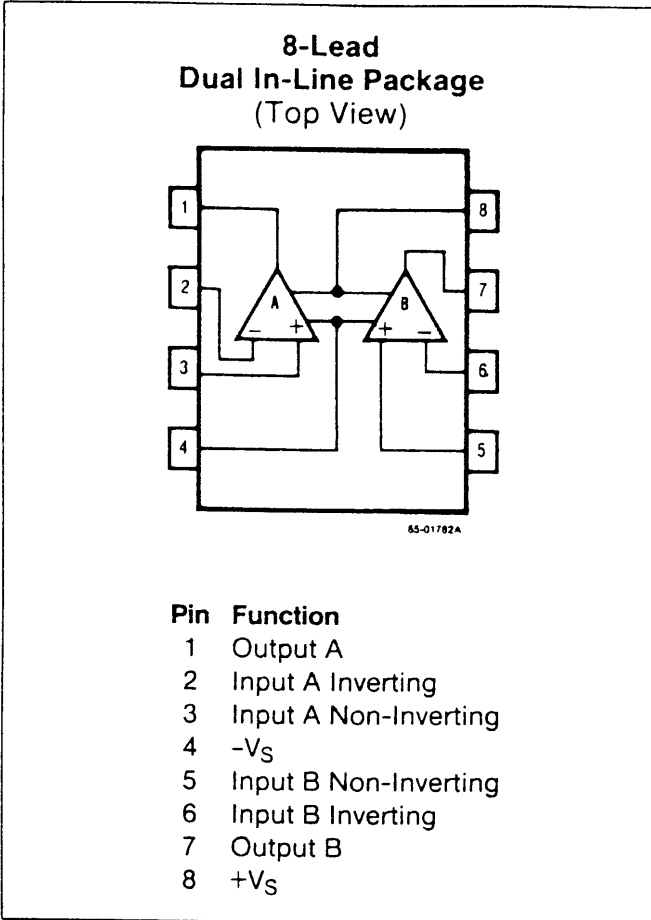
The 4227 is especially useful for instrumentation and professional quality audio systems. The 4227 has an undistorted output up to its power bandwidth frequency of 34kHz, and an undistorted output of  $8.0\text{V}_{\text{p-p}}$  at 100kHz. This device provides performance adequate for the most demanding high fidelity applications.

In addition to providing superior performance for the professional audio market the 4227 design uniquely addresses the needs of the instrumentation designer. Power supply rejection and common mode rejection are both in excess of 120dB. A phase margin of  $70^\circ$  at unity gain guards against peaking (and ringing) in low gain feedback circuits. Stable operation can be obtained with capacitive loads up to  $2000\text{pF}$ <sup>1</sup>. The drift performance is, in fact, so good that the system designer must be cautioned that stray thermoelectric voltages generated by dissimilar metals at the contacts to the input terminals are enough to degrade its performance. For this reason it is also important to keep both input terminals at the same relative temperature.

The performance of the 4227 is achieved through the usage of precision amplifier design techniques coupled with a process that combines nitride transistors and capacitors with precision thin-film resistors. The die size savings of nitride capacitors and thin film resistors allow for the 4227 to be offered in an 8-pin minidip package and fit the industry standard dual op amp pinout.

<sup>1</sup>By decoupling the load capacitance with a series resistor of 50 or more, load capacitances larger than  $2000\text{pF}$  can be accommodated.

**Connection Information**



**Absolute Maximum Ratings**

Supply Voltage	.....	+18V
Input Voltage <sup>1</sup>	.....	±18V
Differential Input Voltage	.....	0.7V
Internal Power Dissipation	.....	658mW
Output Short Circuit Duration	.....	Indefinite
Storage Temperature		
Range	.....	-65° C to +150° C
Operating Temperature Range		
4227B	.....	-55° C to +125° C
4227F/G	.....	0° C to +70° C
Lead Soldering Temperature		
(60 Sec)	.....	+300° C

<sup>1</sup>For supply voltages less than ±18V, the absolute maximum input voltage is equal to the supply voltage.

**Thermal Characteristics**

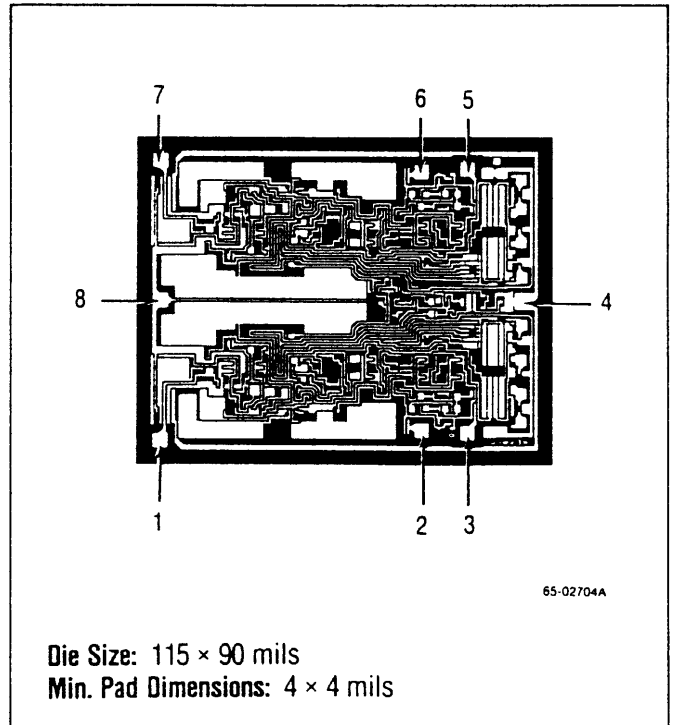
	8-Lead Ceramic DIP	8-Lead Plastic DIP
Max. Junction Temp.	175° C	125° C
Max. P <sub>D</sub> T <sub>A</sub> < 50° C	833mW	468mW
Therm. Res. θ <sub>JC</sub>	45° C/W	---

**Ordering Information**

Part Number	Package	Operating Temperature Range
RC4227FDE	Ceramic	0° C to +70° C
RC4227GDE	Ceramic	0° C to +70° C
RC4227FNB	Plastic	0° C to +70° C
RC4227GNB	Plastic	0° C to +70° C
RM4227BDE	Ceramic	-55° C to +125° C
RM4227BDE/883B*	Ceramic	-55° C to +125° C

\*MIL-STD-883, Level B Processing

**Mask Pattern**



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**Electrical Characteristics** ( $V_S = \pm 15V$  and  $T_A = +25^\circ C$  unless otherwise noted)

Parameters	Test Conditions	4227B/F			4227G			Units
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage <sup>3</sup>			20	75		30	150	$\mu V$
Long Term Input Offset Voltage Stability <sup>1</sup>			0.3			0.4		$\mu V/Mo$
Input Offset Current			$\pm 9.0$	$\pm 50$		$\pm 12$	$\pm 75$	nA
Input Bias Current			$\pm 12$	$\pm 55$		$\pm 15$	$\pm 80$	nA
Input Noise Voltage	0.1Hz to 10Hz		0.08			0.08		$\mu V_{p-p}$
Input Noise Voltage Density	$f_0 = 10Hz$		3.8			3.8		$\frac{nV}{\sqrt{Hz}}$
	$f_0 = 30Hz$		3.3			3.3		
	$f_0 = 1000Hz$		3.2			3.2		
Input Noise Current Density	$f_0 = 10Hz$		1.7			1.7		$\frac{pA}{\sqrt{Hz}}$
	$f_0 = 30Hz$		1.0			1.0		
	$f_0 = 1000Hz$		0.4			0.4		
Input Resistance (Diff. Mode)			5.0			4.0		$M\Omega$
Input Resistance (Com. Mode)			2.5			2.0		$G\Omega$
Input Voltage Range <sup>2</sup>		$\pm 11$	$\pm 12.3$		$\pm 11$	$\pm 12.3$		V
Common Mode Rejection Ratio	$V_{CM} = \pm 11V$	100	123		90	120		dB
Power Supply Rejection Ratio	$V_S = \pm 4.0V$ to $\pm 16.5V$	100	120		90	118		dB
Large Signal Voltage Gain	$R_L \geq 2.0k\Omega$ , $V_O = \pm 10V$	250	800		100	700		V/mV
	$R_L \geq 1.0k\Omega$ , $V_O = \pm 10V$	150	400			400		
	$V_O = \pm 1.0V$ , $V_S = \pm 4.0V$ $R_L \geq 1.0k\Omega$	100	200		75	200		
Output Voltage Swing	$R_L \geq 2.0k\Omega$	$\pm 12$	$\pm 13.8$		$\pm 12$	$\pm 13.8$		V
	$R_L \geq 1k\Omega$	$\pm 11$	$\pm 12$		$\pm 11$	$\pm 12$		
Slew Rate <sup>2</sup>	$R_L \geq 2.0k\Omega$	1.5	2.7		1.5	2.7		$V/\mu S$
Gain Bandwidth Product <sup>2</sup>		5.0	8.0		5.0	8.0		MHz
Open Loop Output Resistance	$V_O = 0$ , $I_O = 0$		70			70		$\Omega$
Power Consumption	$R_L = \infty$		180	240		180	300	mW
Crosstalk		110	126		110	126		dB

Notes: 1. Long Term Input Offset Voltage Stability refers to the average trend line of  $V_{OS}$  vs. Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in  $V_{OS}$  during the first 30 operating days are typically  $2.5\mu V$ .

2. Guaranteed by design.

3. Input Offset Voltage measurements are performed by automated test equipment approximately .5 seconds after application of power.

Caution: The input protection diodes do not allow the device to be removed or inserted into the circuit without first removing power.

**Electrical Characteristics** ( $V_S = \pm 15V$ ,  $-55^\circ C \leq T_A \leq +125^\circ C$  unless otherwise noted)

Parameters	Test Conditions	4227B			Units
		Min	Typ	Max	
Input Offset Voltage <sup>1</sup>			50	200	$\mu V$
Average Input Offset Voltage Drift <sup>2</sup>			0.3	1.3	$\mu V/^\circ C$
Input Offset Current			$\pm 22$	$\pm 95$	nA
Input Bias Current			$\pm 28$	$\pm 95$	nA
Input Voltage Range		$\pm 10$	$\pm 11.5$		V
Common Mode Rejection Ratio	$V_{CM} = \pm 10V$	90	119		dB
Power Supply Rejection Ratio	$V_S = \pm 4V$ to $\pm 16.5V$	94	114		dB
Large Signal Voltage Gain	$R_L > 2.0k\Omega$ , $V_O = \pm 10V$	100	300		V/mV
Output Voltage Swing	$R_L > 2.0k\Omega$	$\pm 11$	$\pm 13.2$		V
Power Consumption	$R_L = \infty$		240	360	mW

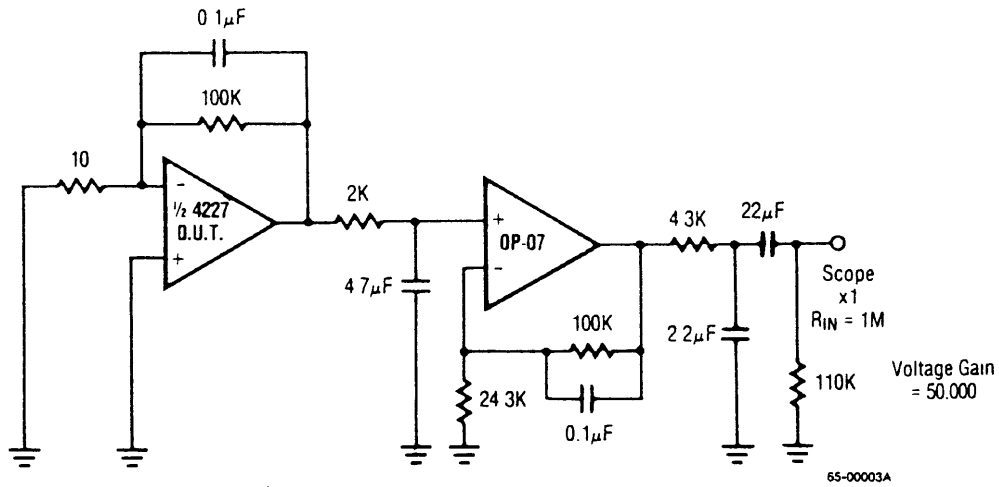
- Notes: 1. Input offset voltage measurements are performed by automated test equipment approximately 0.5 seconds after application of power.  
2. This parameter is tested on a sample basis only.

**Electrical Characteristics** ( $V_S = \pm 15V$ ,  $0^\circ C \leq T_A \leq +70^\circ C$  unless otherwise noted)

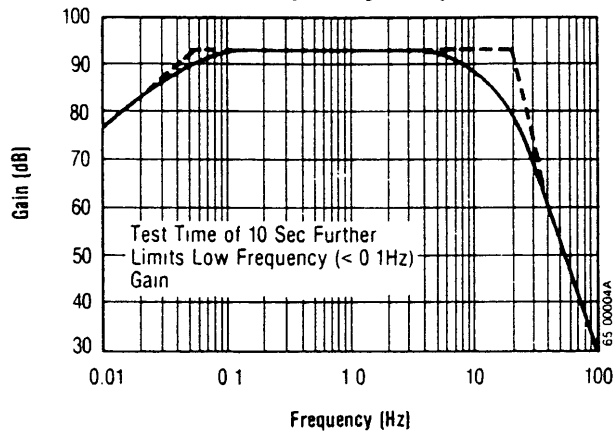
Parameters	Test Conditions	4227F			4227G			Units
		Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage			40	150		85	250	$\mu V$
Average Input Offset Voltage Drift <sup>2</sup>			0.3	1.3		0.4		$\mu V/^\circ C$
Input Offset Current			$\pm 14$	$\pm 95$		$\pm 20$	$\pm 135$	nA
Input Bias Current			$\pm 18$	$\pm 95$		$\pm 25$	$\pm 150$	nA
Input Voltage Range		$\pm 10$	$\pm 11.8$		$\pm 10$	$\pm 11.8$		V
Common Mode Rejection Ratio	$V_{CM} = \pm 10V$	90	121		85	118		dB
Power Supply Rejection Ratio	$V_S = \pm 4V$ to $\pm 16.5V$	94	116		90	114		dB
Large Signal Voltage Gain	$R_L > 2.0k\Omega$ , $V_O = \pm 10V$	100	500		75	500		V/mV
Output Voltage Swing	$R_L > 2.0k\Omega$	$\pm 11$	$\pm 13.5$		$\pm 11$	$\pm 13.5$		V
Power Consumption	$R_L = \infty$		240	360		240	360	mW

### Typical Performance Characteristics

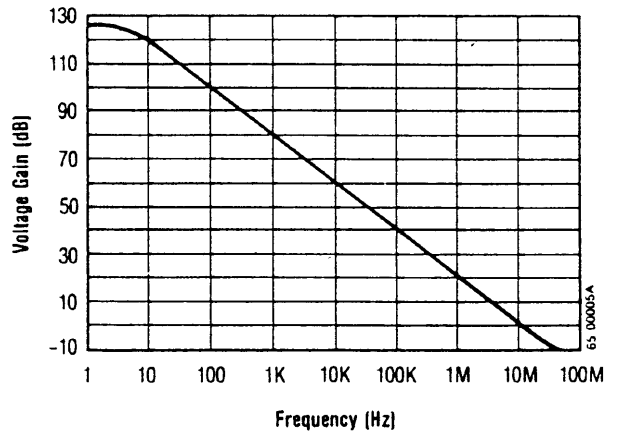
0.1Hz to 10Hz Noise Test Circuit (1/2 Shown)



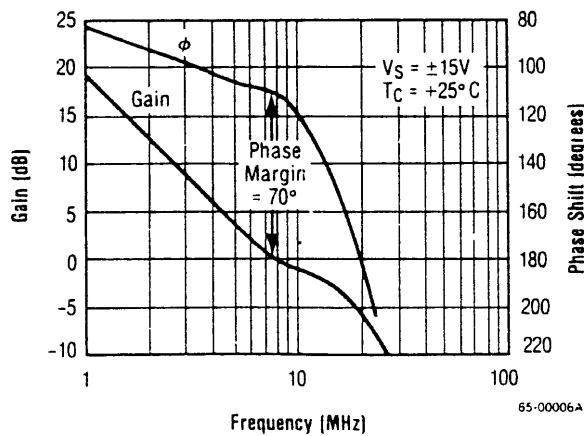
0.1Hz to 10Hz Peak-to-Peak Noise Tester Frequency Response



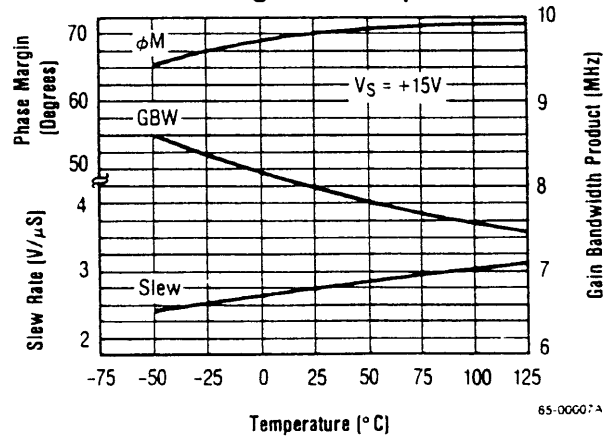
Open Loop Gain vs. Frequency



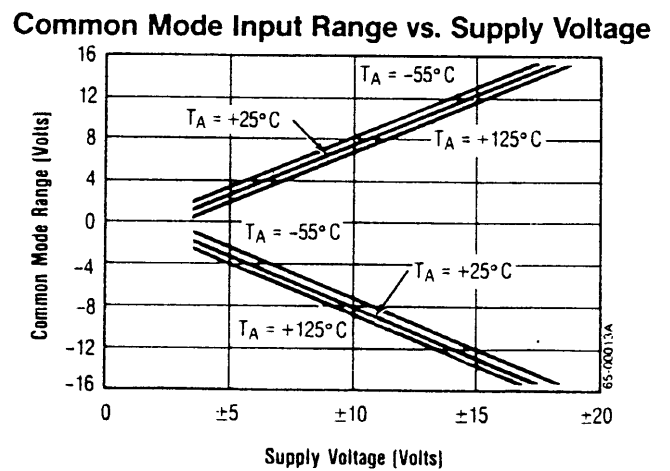
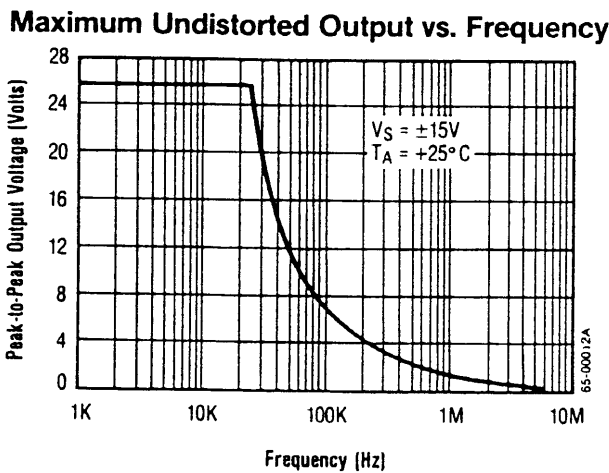
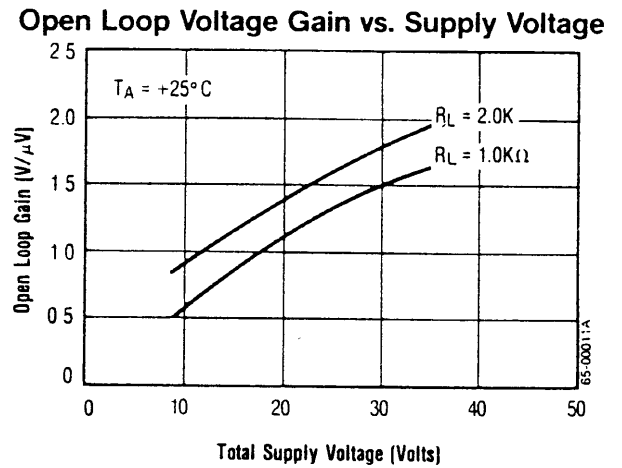
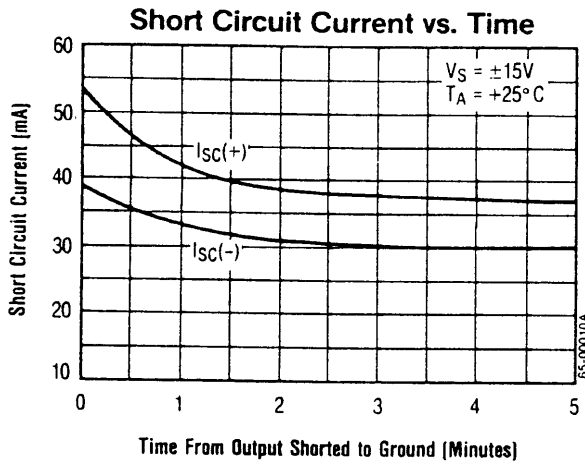
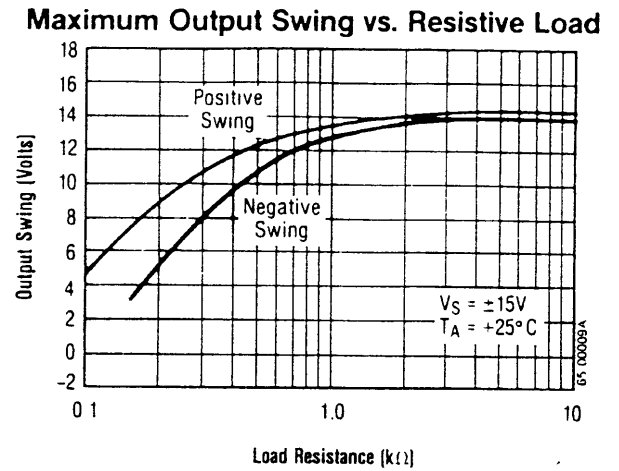
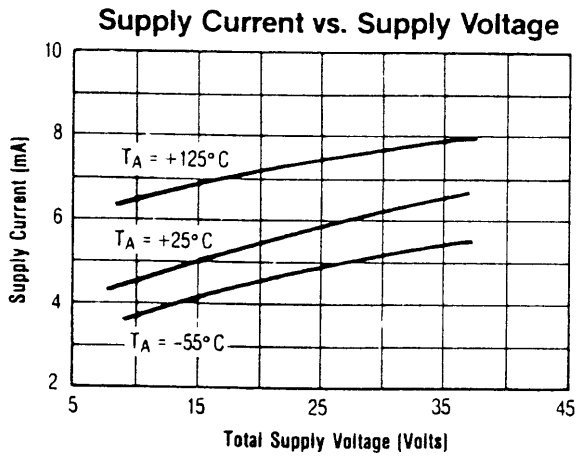
Gain, Phase Shift vs. Frequency



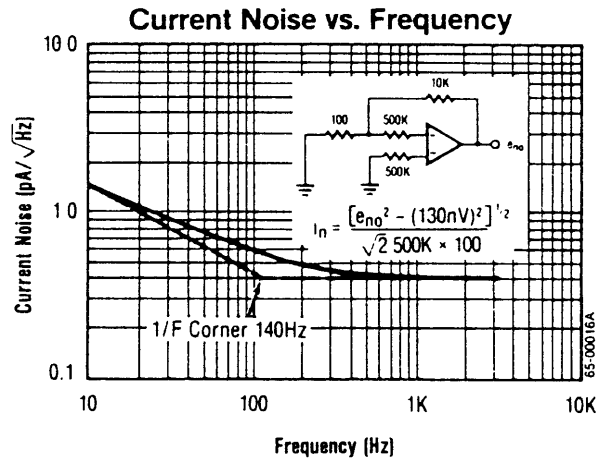
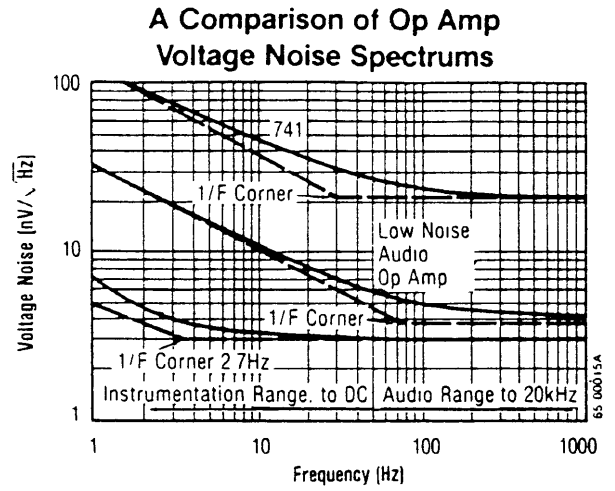
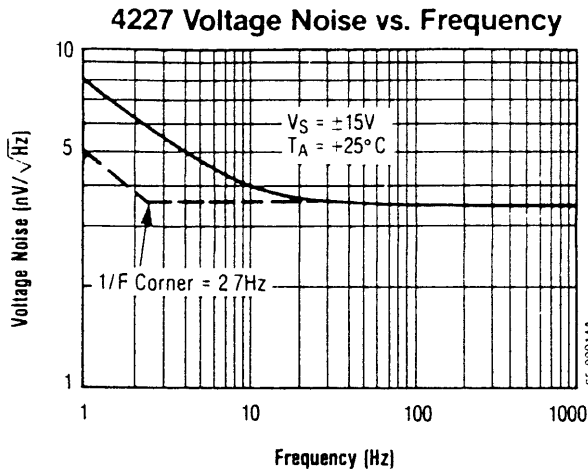
Slew Rate, Gain Bandwidth Product, Phase Margin vs. Temperature



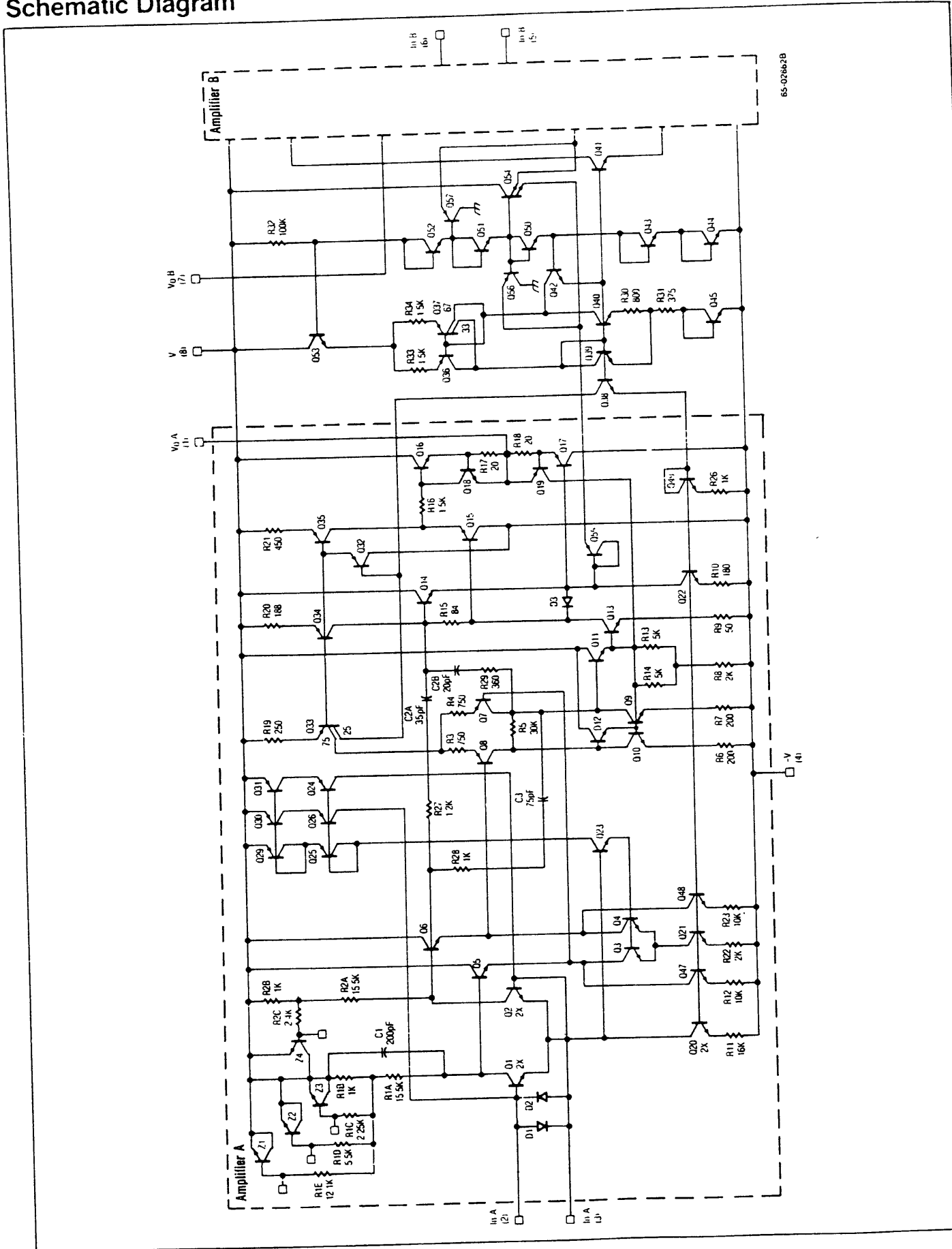
Typical Performance Characteristics (Continued)



Typical Performance Characteristics (Continued)



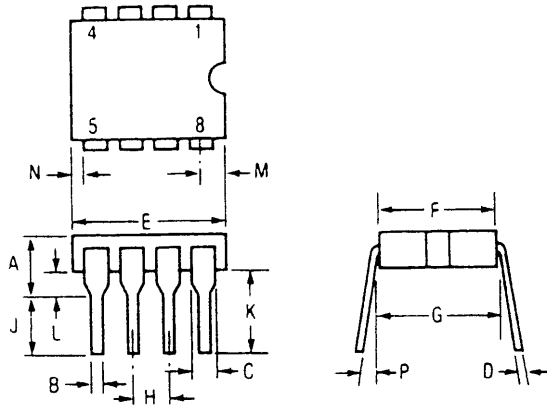
Schematic Diagram





### Packaging Information

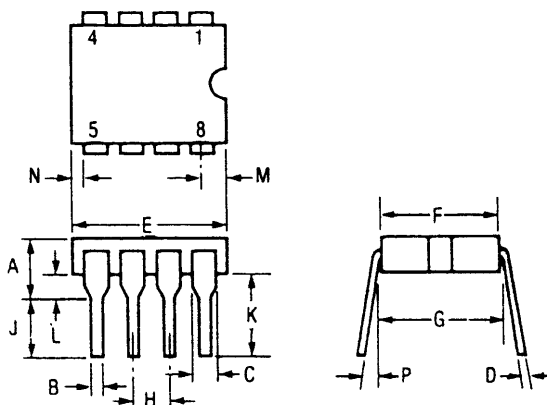
#### 8-Lead Ceramic Dual In-Line Package



Dimension	Inches		Millimeters	
	Min.	Max.	Min.	Max.
A		200		5.08
B	.014	.023	0.36	0.58
C	.030	.070	0.76	1.78
D	.008	.015	0.20	0.38
E		.390		9.91
F	.220	.310	5.59	7.87
G	.290	.320	7.37	8.13
H	100 BSC		2.54 BSC	
J	.125	.200	3.18	5.08
K	.150		3.81	
L	.015	.060	0.38	1.52
M		.045		1.14
N	.005		0.13	
P	0°	15°	0°	15°

65-01203B

#### 8-Lead Plastic Dual In-Line Package



Dimension	Inches		Millimeters	
	Min.	Max.	Min.	Max.
A	.115	.125	2.92	3.17
B	.015	.021	0.38	0.53
C	.030	.070	0.76	1.78
D	.010	.015	0.25	0.38
E	.360	.400	9.14	10.16
F	.240	.260	6.09	6.60
G	.290	.310	7.37	7.87
H	.090	.110	2.29	2.79
J	.120	.135	3.05	3.43
K	.140	.165	3.56	4.18
L	.020	.030	0.51	0.75
M	.025	.050	0.64	1.27
N	.005		0.13	
P	0°	15°	0°	15°

65-01192B